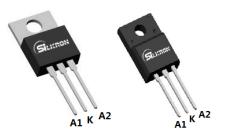
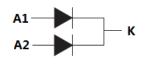


SSBD10L45CT/CTF

Main Product Characteristics:

IF	2×5A
VRRM	45V
T _j (max)	150 ℃
Vf(max)	0.5V





TO220 SSBD10L45CT TO220F SSBD10L45CTF

Schematic Diagram

Features and Benefits:

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability



Description:

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC convertors; this product special design for high forward and reverse surge capability

Absolute Rating:

Symbol	Characterizes	Value	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	45	V	
$V_{R(RMS)}$	RMS Reverse Voltage	31	V	
	Average Femueral Current	Per diode	5	Α
I _{F(AV)}	Average Forward Current	Per device	10	Α
I _{FSM}	Non Repetitive Surge Forward Curre	180	Α	
I _{RRM}	Peak Repetitive Reverse Surge Curr	2	Α	
TJ	Maximum operation Junction Temper	-55~150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	

Thermal Resistance

Symbol	Characterizes	Value	Unit	
$R_{ heta JC}$	Maximum Thermal Resistance Junction To	2	℃W	
$R_{ heta JC}$	Case(per leg)	TO220F	4	℃W

Electrical Characterizes @T_A=25℃ unless otherwise specified

Symbol	Characterizes	Min	Тур	Max	Unit	Test Condition
V_R	Reverse Breakdown Voltage	45			>	I _R =0.5mA
V _F Forward Voltage Drop				0.5	\/	I _F =5A, T _J =25℃
				0.45	V	I _F =5A, T _J =125℃
I _R	Leakage Current			0.1	mA	V _R =45V, T _J =25℃
				20		V _R =45V, T _J =125℃

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I-V Curves:

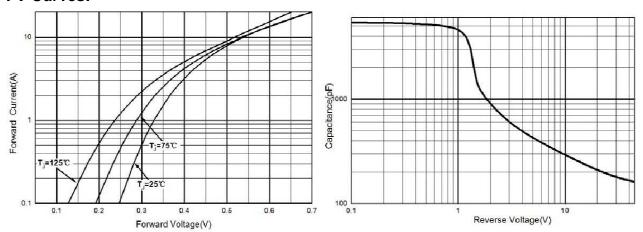


Figure 1: Typical Forward Characteristics Figure 2: Typical Capacitance Characteristics

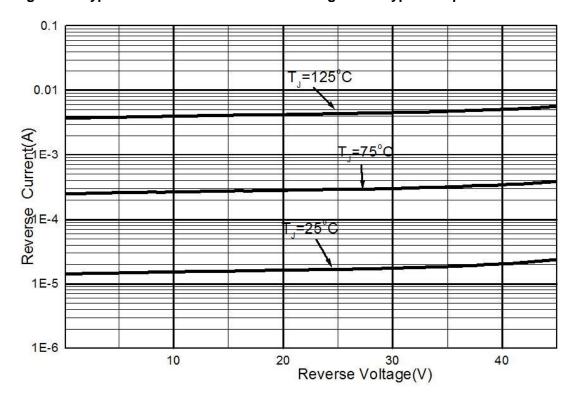
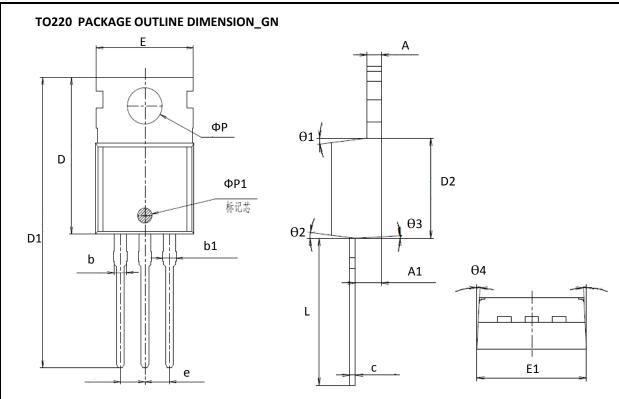


Figure 3: Typical Reverse Characteristics



Mechanical Data:

TO220:

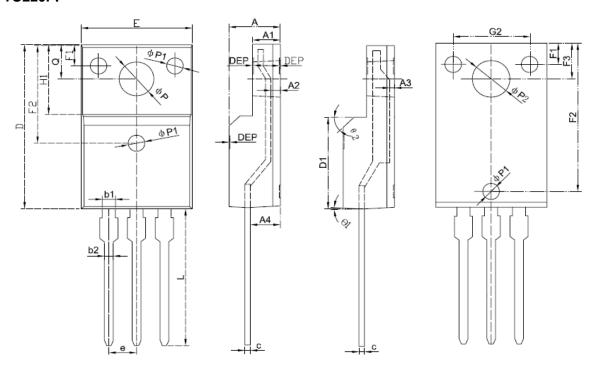


Symbol	Dimension In Millimeters			Dimension In Inches		
Symbol	Min	Nom	Max	Min	Nom	Max
Α	-	1.300	-	-	0.051	-
A1	2.200	2.400	2.600	0.087	0.094	0.102
b	-	1.270	-	-	0.050	-
b1	1.270	1.370	1.470	0.050	0.054	0.058
С	-	0.500	-	-	0.020	-
D	-	15.600	-	-	0.614	-
D1	-	28.700	-	-	1.130	-
D2	-	9.150	-	-	0.360	-
Е	9.900	10.000	10.100	0.390	0.394	0.398
E1	-	10.160	-	-	0.400	-
ΦР	-	3.600	-	-	0.142	-
ФР1		1.500			0.059	
е		2.54BSC			0.1BSC	
L	12.900	13.100	13.300	0.508	0.516	0.524
Θ1	-	7 ⁰	-	-	7 ⁰	-
Θ2	-	7 ⁰	-	-	7 ⁰	-
Θ3	-	3 ⁰	-	5 ⁰	7 ⁰	90
Θ4	-	3 ⁰	-	1 ⁰	3 ⁰	5 ⁰





TO220F:



Cumbal	Dimension In Millimeters			Dimension In Inches		
Symbol	Min	Nom	Max	Min	Nom	Max
E	9.960	10.160	10.360	0.392	0.400	0.408
Α	4.500	4.700	4.900	0.177	0.185	0.193
A1	2.340	2.540	2.740	0.092	0.100	0.108
A2	0.950	1.050	1.150	0.037	0.041	0.045
A3	0.420	0.520	0.620	0.017	0.020	0.024
A4	2.650	2.750	2.850	0.104	0.108	0.112
С	-	0.500	-	-	0.020	-
D	15.670	15.870	16.070	0.617	0.625	0.633
Q	3.200	3.300	3.400	0.126	0.130	0.134
H1	6.480	6.680	6.880	0.255	0.263	0.271
е		2.54BSC		0.10BSC		
ФР	-	3.183	-	-	0.125	-
L	12.780	12.980	13.180	0.503	0.511	0.519
D1	8.990	9.190	9.390	0.354	0.362	0.370
ΦP1	1.400	1.500	1.600	0.055	0.059	0.063
ФР2	-	3.450	-	-	0.136	-
θ1	4°	5°	6°	4°	5°	6°
0 2	-	45°	-	-	45°	-
DEP	0.050	0.100	0.150	0.002	0.004	0.006
F1	1.900	2.000	2.100	0.075	0.079	0.083
F2	8.980	9.180	9.380	0.354	0.361	0.369
F3	3.200	3.300	3.400	0.126	0.130	0.134
G2	6.900	7.000	7.100	0.272	0.276	0.280
b1	1.170	1.205	1.240	0.046	0.047	0.049
b2	0.770	0.810	0.850	0.030	0.032	0.033



SSBD10L45CT/CTF

Ordering and Marking Information

Device Marking: SSBD10L45CT&SSBD10L45CTF

Package (Available)
TO-220&TO220F
Operating Temperature Range
C:-55 to 150 °C

Devices per Unit

Packag e Type	Units/ Tube	Tubes/Inne r Box	Units/Inne r Box	Inner Boxes/Carton Box	Units/Carto n Box
TO220	50	20	1000	6	6000
TO220F	50	20	1000	6	6000

Reliability Test Program

Test Item	Conditions	Duration	Sample Size
High	Tj=125℃ to 175℃ @	168 hours	3 lots x 77 devices
Temperature	80% of Max	500 hours	
Reverse	VDSS/VCES/VR	1000 hours	
Bias(HTRB)			

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